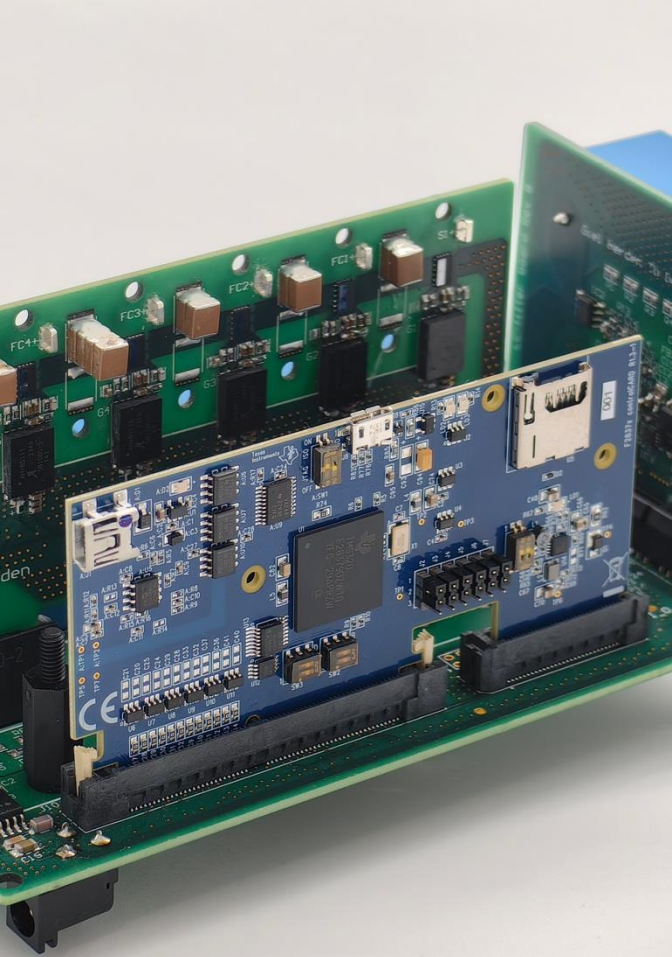




Power converters in motor drives

Components, topology and modulation

Prof. dr. ir. Pavol Bauer



Lecture Outline

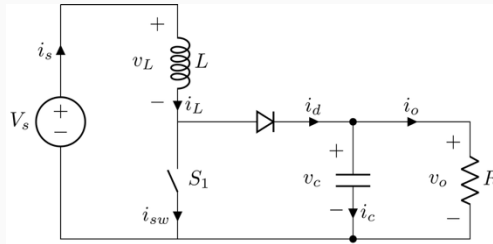
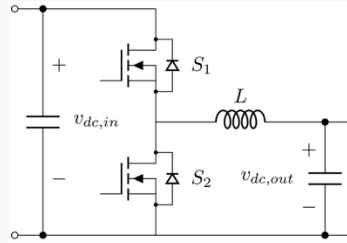
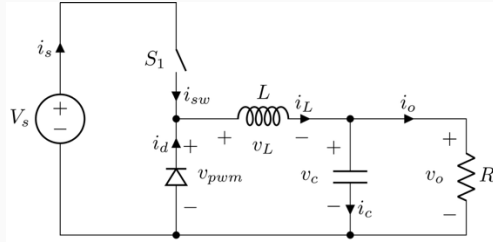
- 1 Types of power converters
- 2 Power converter components
- 3 Power semiconductors
- 4 Basic building block: half-bridge
- 5 H-bridge converter and its modulation

**What power converters
you may see in motor
drives?**

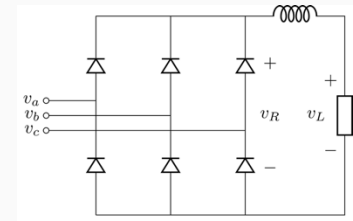
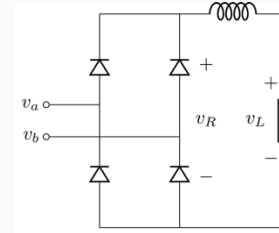
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Power converter types

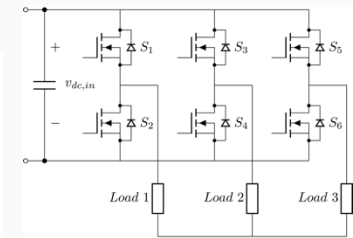
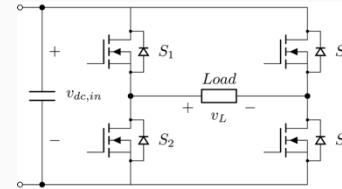
DC-DC



AC-DC (rectifier)



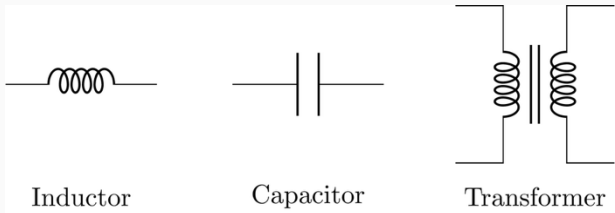
DC-AC (inverter)



**What components are
there inside power
converters?**

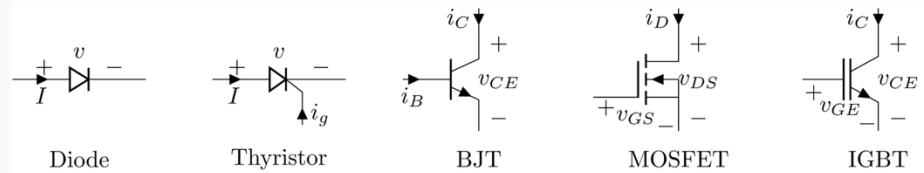


Passive components



- **Inductor**: store energy and stabilize current (di/dt limiter)
- **Capacitor**: store energy and stabilize voltage (dv/dt limiter)
- **Transformer**: introduce a conversion ratio or galvanic isolation

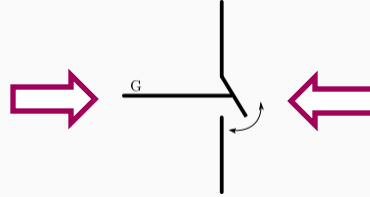
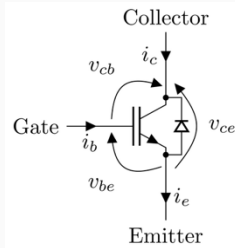
Switching components



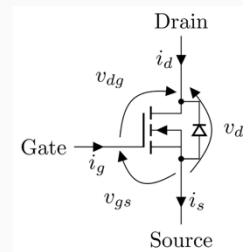
- **Diode**: only let go forward current, no gate operable
- **Thyristor/BJT**: gate current controlled
- **MOSFET/IGBT**: gate voltage controlled (mainstream in motor drive)

Power semiconductors: IGBT and MOSFET

Power IGBT (with antiparallel diode)



Power MOSFET

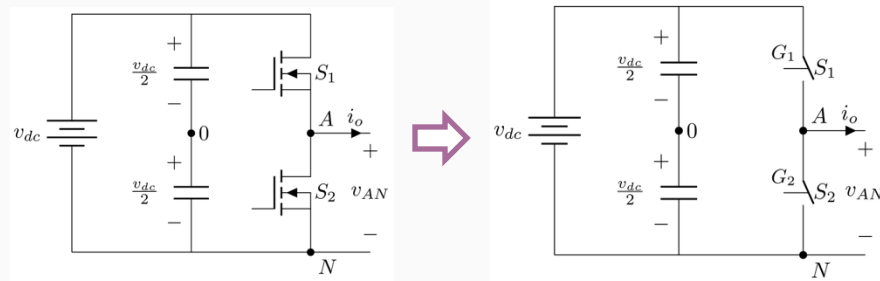


- Insulated-gate bipolar transistor
 $v_G > v_E$ ($v_{be} > \text{threshold}$): on, $i_c \approx i_e$
 $v_{ce} \approx \text{small constant}$
 $v_G < v_E$ ($v_{be} < \text{threshold}$): off, $i_c \approx 0$
- Antiparallel diode needed for reverse current flow
- Medium switching speed (ns-us)
- Very high rated voltage and current

- Metal-oxide-semiconductor field-effect transistor
 $v_G > v_S$ ($v_{gs} > \text{threshold}$): on, $i_d \approx i_s$
 $v_{ce} \approx i_d R_{ds,on}$, $R_{ds,on} \approx \text{small constant}$
 $v_G < v_S$ ($v_{gs} < \text{threshold}$): off, $R_{ds,off} \approx \infty$
- Internal body diode
- Fast switching speed (ns)
- Lower rated voltage and current

**How to construct power
converters from these
components?**

Half bridge: a basic building block



S1 on, S2 off:

- $v_{AN} = v_{dc}; v_{AO} = v_{dc}/2$

S1 off, S2 on:

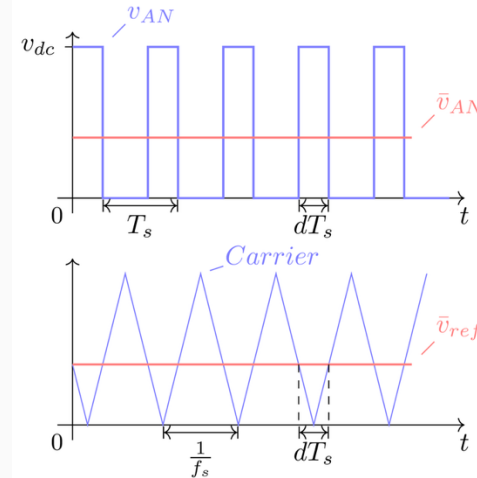
- $v_{an} = 0; v_{AO} = -v_{dc}/2$

In one switching period $T_s = 1/f_s$:

- S1 on, S2 off for $0 \sim dT_s$ interval
- S1 off, S2 on for $dT_s \sim T_s$ interval

To achieve the wanted average voltage:

- Pulse width modulation (PWM)
- Reference voltage v_{ref}
- Triangular carrier waveform
- $v_{ref} > \text{carrier}$: S1 on, S2 off
- $v_{ref} < \text{carrier}$: S1 off, S2 on

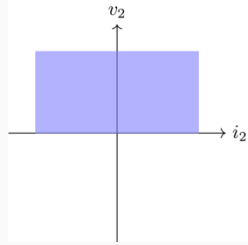
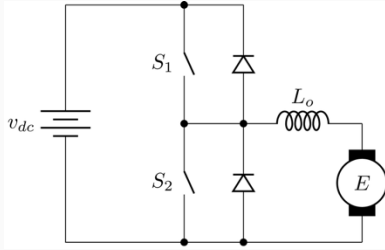


Average output:

$$\bar{v}_{AN} = d v_{dc}$$

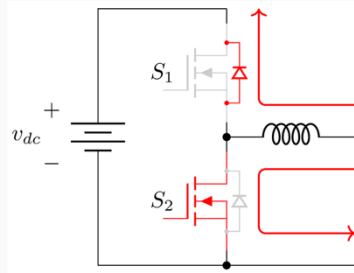
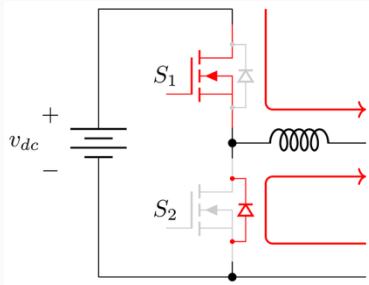
$$\bar{v}_{AO} = (d - 0.5) v_{dc}$$

Half bridge: two-quadrant operation

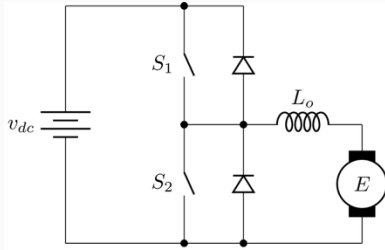


DC motor drive for 2 quadrant operation

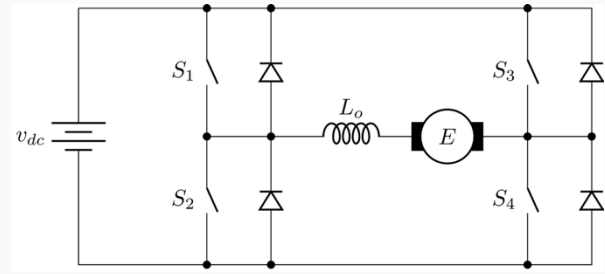
- Turn in forward direction: motor and generator operation.
- **Not able** to turn backward, because the voltage polarity is not able to be reversed.



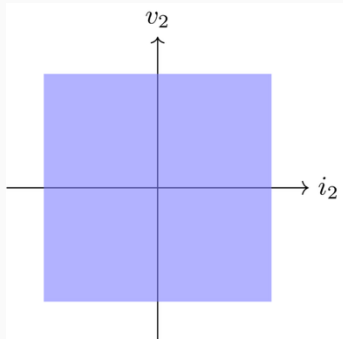
H-bridge: four-quadrant operation



Two-quadrant half-bridge

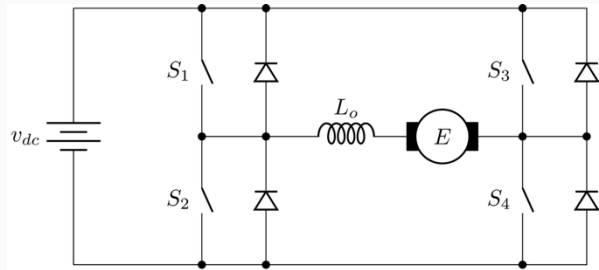


Two half-bridges form a four-quadrant H-bridge



- Voltage polarity reversible
- Can make a DC machine rotate backward
- How to realize the PWM (pulse-width-modulation)?

H-bridge: bipolar modulation



- S1, S4 and S2, S3 are switched **in pairs**, complementarily
- output V_o is switching **between $+V_{dc}$ and $-V_{dc}$** (bipolar PWM).
- Therefore negative V_o is possible.

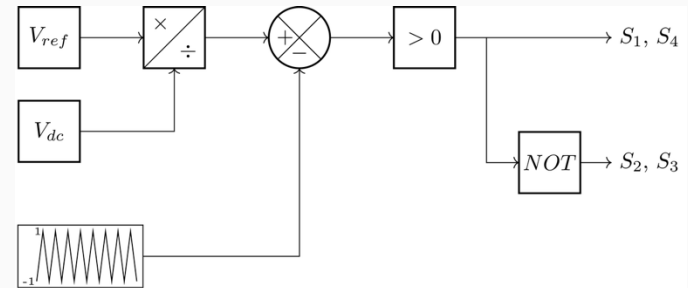
d_1 : duty cycle of S1, S4

d_2 : duty cycle of S2, S3

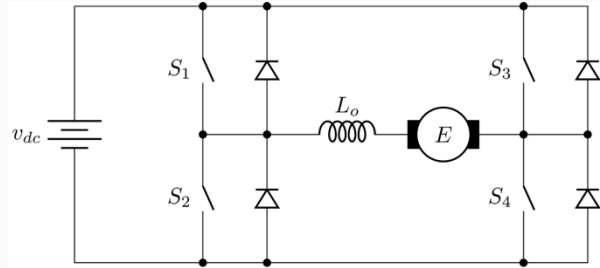
- Complementary switching: $d_1 + d_2 = 1$
- Averaged output voltage:

$$v_o = d_1 V_{dc} - d_2 V_{dc} = (2d_1 - 1)V_{dc}$$

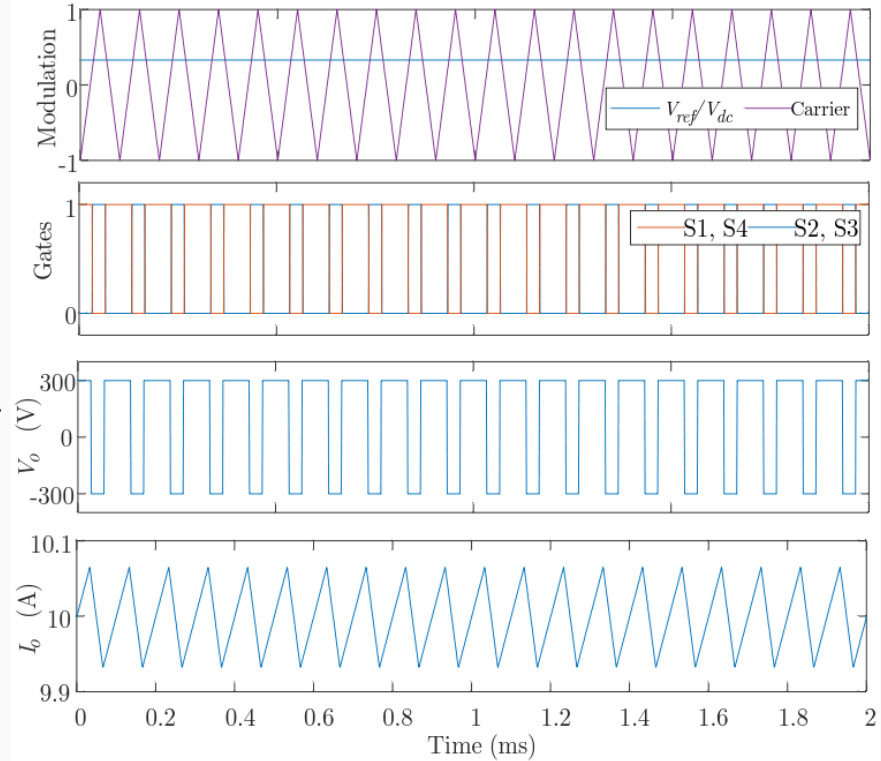
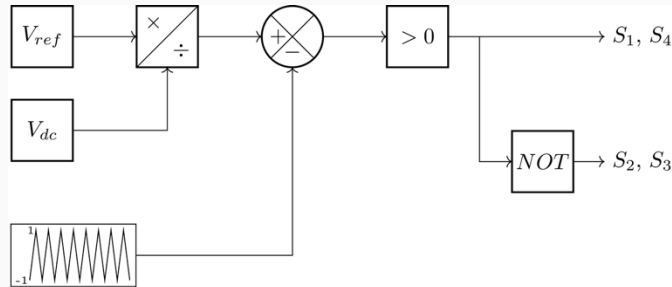
- Modulation:



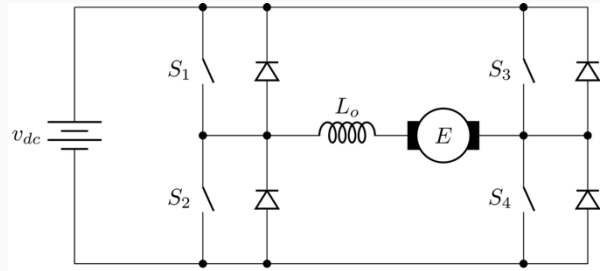
H-bridge bipolar modulation waveforms



- S1, S3 and S2, S4 are switched **in pairs**, complementarily
- output V_o is switching **between $+V_{dc}$ and $-V_{dc}$** (bipolar PWM).



H-bridge: unipolar modulation



- S1, S2 switch complementary, so are S3, S4.
- V_o is switching either between $+V_{dc}$ and 0 or between $-V_{dc}$ and 0 (uni-polar PWM)
- Less current ripple compared to bi-polar switching

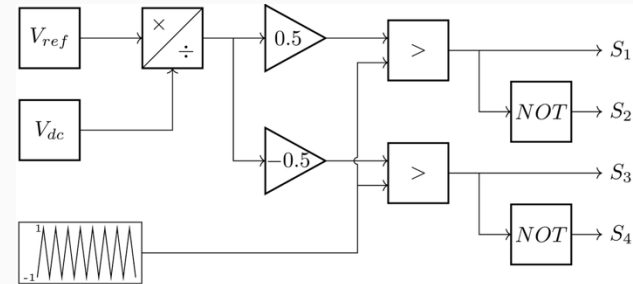
d_1 : duty cycle of S_1

d_3 : duty cycle of S_3

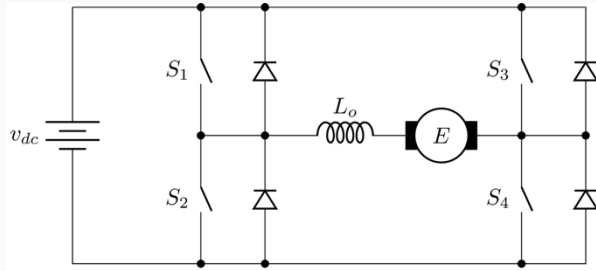
- Complementary switching: $d_1 + d_2 = 1$, $d_3 + d_4 = 1$
- Averaged output voltage:

$$v_o = d_1 V_{dc} - d_3 V_{dc}$$

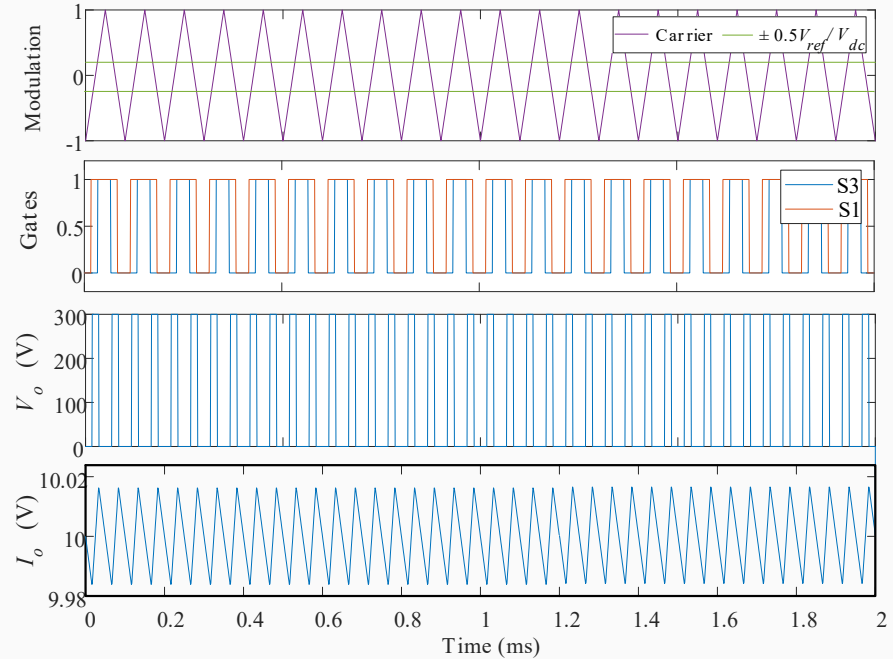
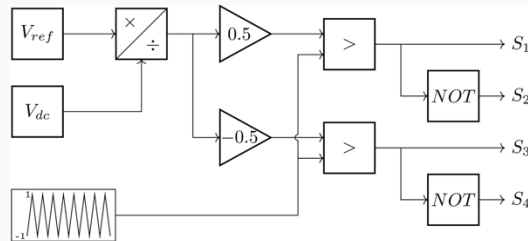
- Modulation:



H-bridge unipolar modulation waveforms

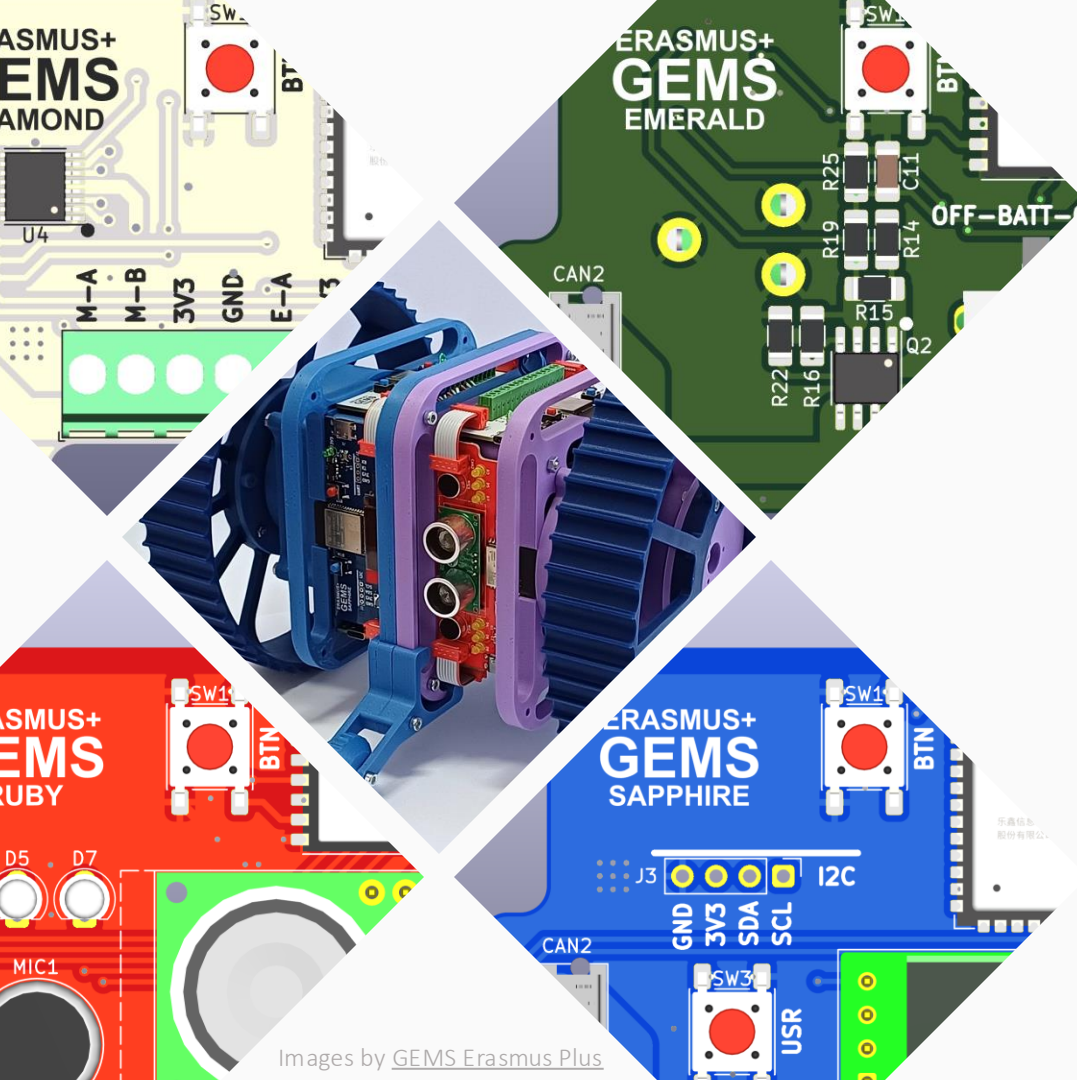


- S1, S2 switch complementary, so are S3, S4.
- V_o is switching either between $+V_{dc}$ and 0 or between $-V_{dc}$ and 0 (uni-polar PWM)
- Less current ripple compared to bi-polar switching



Conclusions

- Power converters are built based on **passive components** (LC) and **power semiconductors** (IGBT, MOSFET, diode etc.)
- Voltage controlled devices (Power MOSFET and IGBT) are commonly used in modern drives.
- A **half-bridge** is able to drive a DC motor in **two quadrants**, but without ability to reverse rotation.
- A full-bridge (**H-bridge**) is able to drive DC motor in **four quadrants**.
- H-bridge can be modulated in either bipolar or unipolar modes.



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